

Monolithic Amplifier PMA-545G2+

1.1 to 1.6 GHz

THE BIG DEAL

- · High Gain, 30.4 dB typ. at 1.4 GHz
- Ultra Low Noise Figure, 1.0 dB typ. at 1.4 GHz
- · High IP3, 34 dBm typ. at 1.4 GHz
- Output Power, up to +22dBm typ. at 1.4 GHz
- Single Positive Supply Voltage, 5V
- · Micro-miniature size 3mm x 3mm
- Aqueous washable
- Protected by U.S. patent no. 8,803,612



Generic photo used for illustration purposes only

CASE STYLE: DQ849

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

- Airborne Radar
- GPS
- INMARSAT

PRODUCT OVERVIEW

Mini-Circuits PMA-545G2+ is a E-PHEMT* based Low Noise MMIC Amplifier operating from 1.2 to 1.6 GHz with a unique combination of low noise and high Gain making this amplifier ideal for sensitive receiver applications. This design operates on a single +5V supply and is internally matched to 50 Ohms.

KEY FEATURES

| Feature | Advantages |
|--|---|
| High Gain: 30 dB | Incorporating multiple stages of amplification, the PMA-545G2+ provides high gain reducing cost and PCB board space. |
| Ultra Low Noise: 1.0 dB NF at 1.4 GHz | Excellent Noise Figure, measured in a 50 Ohm environment – without any external matching. When combined with high gain of this design, it suppresses second stage NF contribution. |
| High IP3: +34 dBm IP3 at 1.4 GHz | Combining Low Noise and High IP3 makes this MMIC amplifier ideal for Low Noise Receiver Front End (RFE) giving the user advantages at both ends of the dynamic range: sensitivity & two-tone IM dynamic range |
| Output Power: +22 dBm at 1.4 GHz | The PMA-545G2+ maintains consistent output power capability over the full operating temperature range making it ideal to be used in remote applications such as LNB's as the L Band driver stage |
| Broad Band: 1.2 to 1.6 GHz | Covering GPS, INMARSAT, Radar |
| Internally Matched | No external matching elements required to achieve the advertized noise and output power over the full band |
| MCLP Package | Low Inductance, repeatable transitions, excellent thermal pad |
| Max Input Power +25dBm | Ruggedized design operates up to input powers often seen at Receiver inputs. Eliminating need for an external limiter. |
| High Reliability | Low, small signal operating current of 160 mA nominal maintains junction temperatures typically below 130°C at 85°C ground lead temperature |

^{*}Enhancement mode Pseudomorphic High Electron Mobility Transistor.

REV. B ECO-010881 PMA-545G2+ TH/RS/CP/AM





Monolithic Amplifier PMA-545G2+

ELECTRICAL SPECIFICATIONS⁽¹⁾ AT 25°C, VD=5V, ZO=50Ω, (REFER TO CHARACTERIZATION CIRCUIT)

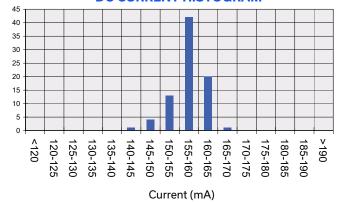
| Parameter | Condition (GHz) | Min. | Тур. | Max. | Units |
|---|-----------------|------|--------|------|-------|
| Frequency Range | | 1.1 | | 1.6 | GHz |
| DC Voltage (V _d) | | 4.8 | 5.0 | 5.2 | V |
| DC Current (I _d) ⁽⁶⁾ | | | 158 | 186 | mA |
| | 1.1 | | 1.0 | | |
| Noise Figure | 1.4 | | 1.0 | 1.4 | dB |
| | 1.6 | | 1.1 | | |
| | 1.1 | | 31.0 | | |
| Gain | 1.4 | 27.2 | 30.4 | 33.4 | dB |
| | 1.6 | | 29.6 | | |
| | 1.1 | | 11.5 | | |
| Input Return Loss | 1.4 | | 13.1 | | dB |
| | 1.6 | | 14.6 | | |
| | 1.1 | | 15.9 | | |
| Output Return Loss | 1.4 | | 14.7 | | dB |
| | 1.6 | | 14.4 | | |
| | 1.1 | | 33.6 | | |
| Output IP3 | 1.4 | | 33.6 | | dBm |
| | 1.6 | | 34.3 | | |
| | 1.1 | | 22.1 | | |
| Output Power @ 1 dB compression (2) | 1.4 | 20.0 | 22.0 | | dBm |
| | 1.6 | | 22.4 | | |
| DC Current Variation vs. Temperature (3) | | | -0.156 | | mA/°C |
| DC Current Variation vs. Voltage | | | 0.027 | | mA/mV |
| Thermal Resistance | | | 48 | | °C/W |

MAXIMUM RATINGS(4)

| Parameter | Ratings |
|---------------------------|----------------|
| Operating Temperature (5) | -40°C to 85°C |
| Storage Temperature | -65°C to 150°C |
| Channel Temperature | 150°C |
| DC Voltage (Pad 4,5,7) | 6V |
| Power Dissipation | 1.35W |
| Input Power | 25dBm |

- (1) Measured on Mini-Circuits Characterization test board TB-607-3+ See Characterizatio Test Circuit (Fig. 1)
- (3) (Current at 85°C Current at -45°C)/130
- (4) Permanent damage may occur if any of these limits are exceeded.
 These maximum ratings are not intended for continuous normal operation.
 (5) Defined with reference to ground pad temperature.

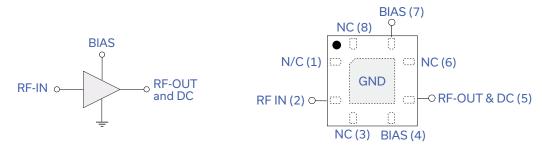
DC CURRENT HISTOGRAM





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SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



| Function | Pad Number | Description (See Application Circuit, Fig. 2) |
|-------------|----------------------------|---|
| RF-IN | 2 | RF input pad (connected to RF-IN via C1) |
| RF-OUT & DC | 5 | RF output pad (connected to RF-OUT via blocking external cap C2, and Supply voltage Vs via RF Choke L2) |
| BIAS | 4 & 7 | Bias pad 4 connects to Vs via L1 & pad 7 connects to Vs |
| GND | paddle in center of bottom | Connected to ground |
| NOT USED | 1,3,6,8 | No internal connection; recommended use: per PCB Layout PL-346 |

CHARACTERIZATION TEST CIRCUIT

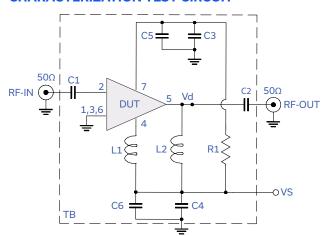


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-607-3) Gain, Output power at 1dB compression (P1dB), Output IP3 (OIP3), Noise Figure are measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

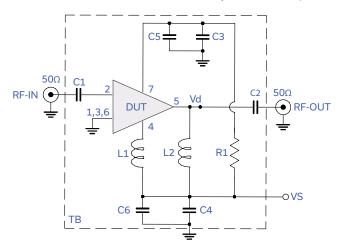
- 1. Gain: Pin=-25 dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
- 3. Vs adjusted for 5V at device (Vd), compensating loss of bias tee.



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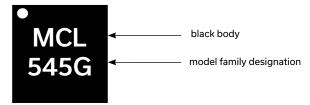
RECOMMENDED APPLICATION CIRCUIT

(refer to evaluation board for PCB Layout and component values)



| Component | Description |
|----------------|-------------|
| DUT | PMA-545G2+ |
| C1, C2, C5, C6 | 100 pF |
| C3, C4 | 1μF |
| R1 | 0 Ω |
| L1 | 36 nH |
| L2 | 47 nH |

PRODUCT MARKING



Marking may contain other features or characters for internal lot control



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS

CLICK HERE

| Performance Data | Data Table graphs, s-parameter data set (.zip file) |
|--|---|
| Case Style | DQ849 Plastic package, exposed paddle, lead finish: tin-silver over nickel |
| Tape & Reel Standard quantities available on reel | F104 7" reels with 20, 50, 100, 200, 500, 1K, or 2K devices. |
| Suggested Layout for PCB Design | PL-346 |
| Evaluation Board | TB-607-2+ |
| Environmental Ratings | ENV08T1 |

ESD RATING

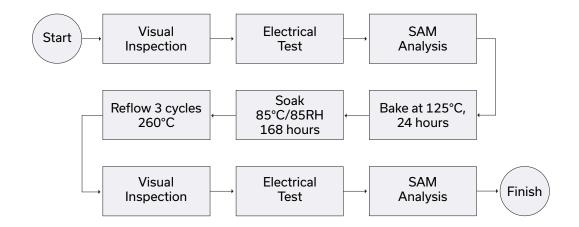
Human Body Model (HBM): Class 1B (500V to <1000V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (passes 40V) in accordance with ANSI/ESD STM5.2-1999; passes 40V

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document

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